

View Online at <https://aerobasegroup.com/nsn/5961-01-157-0362>

**Inclosure Material:**

Ceramic

**Component Name And Quantity:**

5 semiconductor device diode

**Mounting Method:**

Terminal

**Voltage Rating In Volts Per Characteristic:**

15.0 collector to emitter voltage/static/base open all semiconductor device diode and 20.0 collector to base voltage/static/emitter open all semiconductor device diode and 5.0 emitter to base voltage, static, collector open all semiconductor device diode

**Current Rating Per Characteristic:**

20.00 milliamperes zero-gate-voltage source current of standard range all semiconductor device diode and 100.00 milliamperes zero-gate-voltage source current blank all semiconductor device diode

**Power Rating Per Characteristic:**

750.0 milliwatts small-signal input power, common-collector preset all semiconductor

**Maximum Operating Temperature Per Measurement Point:**

125.0 degrees celsius ambient air

**Special Features:**

All semiconductor device diode junction pattern arrangement: pnp

**Terminal Type And Quantity:**

16 printed circuit

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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